

# KBU35005 THRU KBU3510

### Glass Passivated Bridge Rectifiers

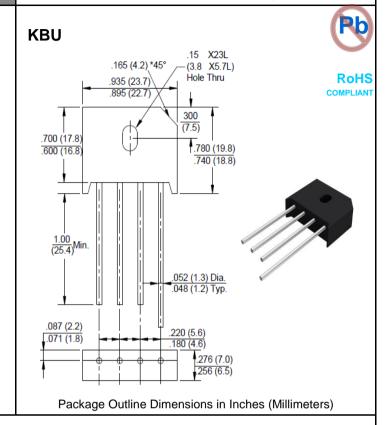
## Reverse Voltage - 50 to 1000 Volts

#### Forward Current - 35 Amperes

Features							
<ul> <li>Glass passivated chip</li> </ul>							
<ul> <li>Low forward voltage drop</li> </ul>							
<ul> <li>Ideal for printed circuit board</li> </ul>							
<ul> <li>High surge current capability</li> </ul>							
Mechanical Data							
<ul> <li>Polarity: Symbol marked on body</li> </ul>							
<ul> <li>Mounting position: Any</li> </ul>							

#### Applications

• General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc.



#### **Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristics	Symbol	KBU	KBU	KBU	KBU	KBU	KBU	KBU	Unit
	Symbol	35005	3501	3502	3504	3506	3508	3510	
Maximum Repetitive Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward (with heatsink Note 1)	I(AV)	35							A
Rectified Current @ Tc=100℃	I(AV)								
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave,	IFSM	350							A
Superimposed on Rated Load (JEDEC Method)	IF SIVI								
I <sup>2</sup> t Rating for Fusing (t<8.3mS)	l <sup>2</sup> t	508.4							A <sup>2</sup> s
Peak Forward Voltage per Diode at 17.5A DC	VF	1.1							V
Maximum DC Reverse Current at Rated @TJ=25°C	IR	10							μA
DC Blocking Voltage per Diode @Tj=125°C	ік	500							
Operating Junction Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	Тѕтс	-55 to +150							°C

# Rating and Characteristic Curves KBU35005 thru KBU3510

